



Technical Data
Data Sheet N0175, Rev. A

Green Products

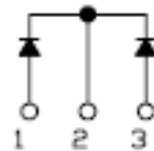
SDURF1040CT(CTR) ULTRAFAST PLASTIC RECTIFIER

Applications:

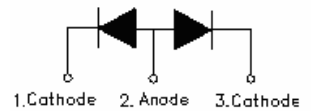
- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

- Fully Molded Isolation
- Dual Diodes-Anode Common
- Ultra-Fast Recovery
- Low Forward Voltage Drop
- High Surge Capability
- 200 Volts thru 600 Volts Types Available
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

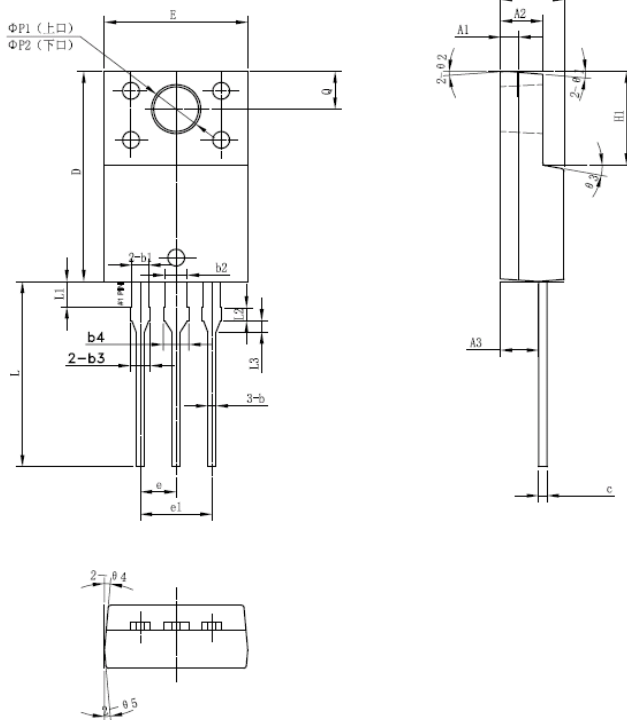


SDURF1040CT



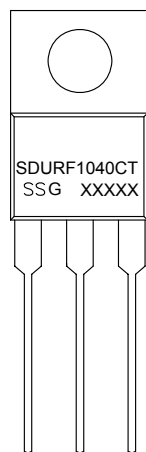
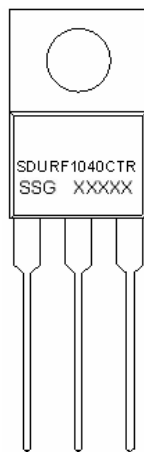
SDURF1040CTR

Mechanical Dimensions: In mm



SYMBOL	MIN.	TYP.	MAX.
A	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.50	0.60	0.75
b1	1.10	1.20	1.35
b2	1.50	1.60	1.75
b3	1.20	1.30	1.45
b4	1.60	1.70	1.85
c	0.55	0.60	0.75
D	14.80	15.00	15.20
E	9.96	10.16	10.36
e		2.55	
e1		5.10	
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	1.20
L3	0.60	0.80	1.00
ΦP1(上口)	3.30	3.50	3.70
ΦP2(下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
θ1		5°	
θ2		4°	
θ3		10°	
θ4		5°	
θ5		5°	

ITO-220AB

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Marking Diagram:

SDURF1040CT

SDURF1040CTR

Where XXXXX is YYWWL

SDUR	= Device Type
F	= Package Type
10	= Forward Current (10A)
40	= Reverse Voltage (400V)
CT/CTR	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin
 Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SDURF1040CT/CTR	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	400	V
Max. Average Forward	$I_{O(AV)}$	50Hz, Sine wave, $T_C=112^\circ\text{C}$	10	A
Max. Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	50Hz, Half Sine wave	80	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop(per leg)	V_F	@ $I_F=5A$, Pulse, $T_J=25^\circ C$	1.3	V
Max. Reverse Current	I_R	@ $V_R = \text{rated } V_R$ $T_J = 25^\circ C$	30	μA
Max. Reverse Recovery Time	t_{rr}	$I_F=500mA$, $I_R=1A$, and $I_{rm}=250mA$	45	ns

* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +150	$^\circ C$
Max. Storage Temperature	T_{stg}	-	-55 to +150	$^\circ C$
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	3.5	$^\circ C / W$
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

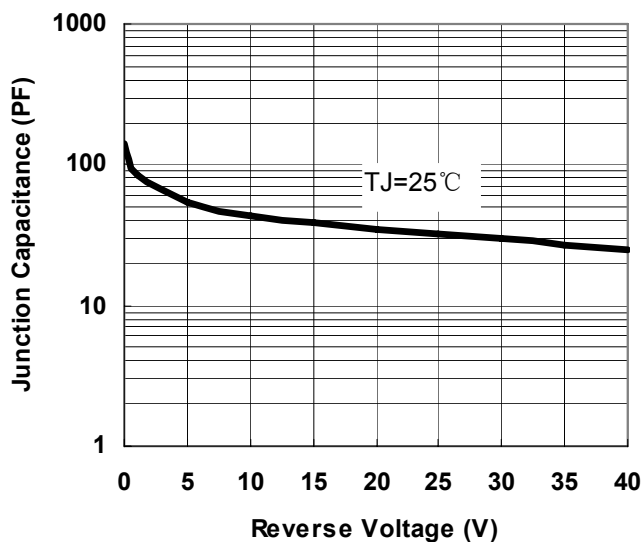


Fig.1-Typical Junction Capacitance

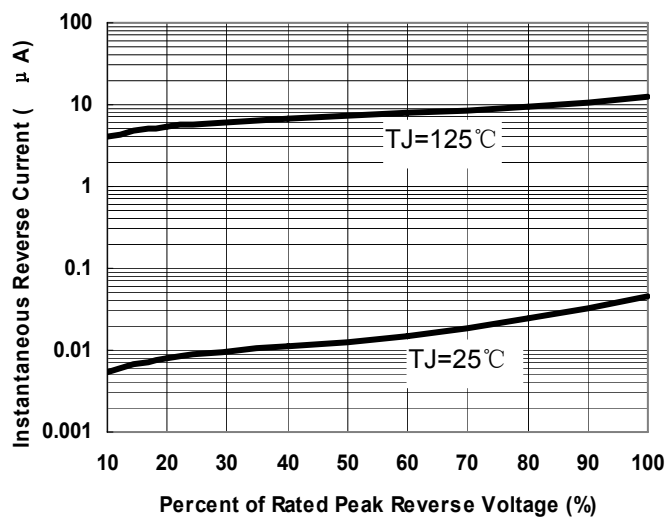


Fig.2-Typical Reverse Characteristics

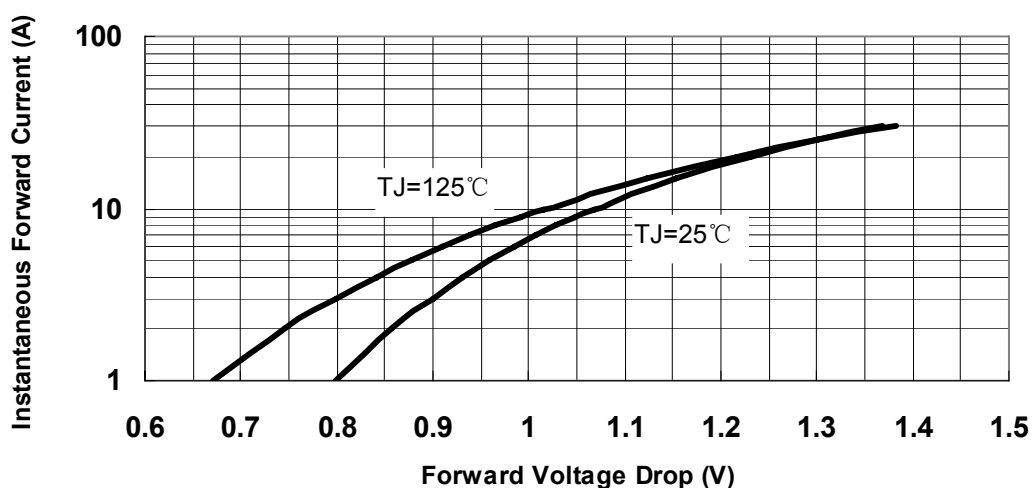


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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